Total No. of Questions—8]

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## F.E. EXAMINATION, 2019

## **ENGINEERING PHYSICS**

## (2015 **PATTERN**)

Time: Two Hours

Maximum Marks: 50

- **N.B.** :— (i) Neat diagrams must be drawn wherever necessary.
  - (ii) Figures to the right indicate full marks.
  - (iii) Use of logarithmic tables, slide, rule, Mollier charts, electronic pocket calculator and steam tables is allowed.
  - (iv) Assume suitable data, if necessary.

Given : 
$$e = 1.6 \times 10^{-19} \text{ C}$$
  
 $h = 6.63 \times 10^{-34} \text{ Js}$   
 $c = 3 \times 10^8 \text{ m/s}$   
 $m_e = 9.1 \times 10^{-31} \text{ kg}$ 

- 1. (a) Explain the theory of formation of Newton's rings. Prove that the diameters of bright rings are proportional to square root of odd natural numbers. [6]
  - (b) Explain the following: [3]
    - (i) Piezoelectric effect
    - (ii) Magnetostriction effectwith diagrams.

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(c) Calculate the depth of sea if the time interval between the emitted signal and the echo received is 2 sec. in SONAR studies.

Assume the velocity in sea water as 1490 m/s. [3]

Or

- 2. (a) Derive the equation for resultant amplitude in Fraunhofer diffraction due to single slit and obtain the conditions to principal maximum and minima. [6]
  - (b) Explain any two factors with remedies which affect architectural acoustics of auditorium. [3]
  - (c) In a Newton's rings experiment, the diameter of certain bright ring is 0.65 cm and that of 10th bright, ring beyond it is 0.95 cm. If  $\lambda = 6000$  Å, calculate the radius of curvature of a convex lens in contact with glass plate. [3]
- 3. (a) Explain Huygen's theory of double refraction.
  - (b) Draw the energy band diagrams for p-n junction diode in :
    - (1) Zero bias
    - (2) Forward bias
    - (3) Reverse bias conditions. [3]
  - (c) Calculate the conductivity of pure silicon at room temperature when the concentration of charge carriers is  $1.6 \times 10^{10}$  per cm<sup>3</sup>. Given :  $\mu_e = 1500$  cm<sup>2</sup>/volt-sec,  $\mu_h = 500$  cm<sup>2</sup>/volt-sec.

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4.	(a)	Define Fermi level in conductors. Using Fermi-Dirac probabil	lity	
		distribution function, show that Fermi level in int		
		semiconductor lies exactly at centre of the band gap.	[6]	
	( <i>b</i> )	Explain the following:	[3]	
		(i) Stimulated emission		
		(ii) Population inversion		
		(iii) Metastable state.		
	(c)	Explain the construction process in holographic technique.	[3]	
<b>5.</b>	(a)	Derive Schrodinger's time independent wave equation.	[6]	
	( <i>b</i> )	State de Broglie hypothesis. Derive the equation for de Brog	glie	
		wavelength in terms of kinetic energy.	[4]	
	( <i>c</i> )	An electron in an infinite potential well is in ground sta	ate.	
		Find the fourth energy level of electron in eV.	[3]	
			3	
		Or		
<b>6.</b>	( <i>a</i> )	Define phase velocity and group velocity.	[6]	
		Show that		
		(i) Phase velocity of matter waves is $e^{2}v$ .		
		(ii) Group velocity of matter waves is equal to particle velocity	ity.	
	<i>(b)</i>	Explain the physical significance of wave function $\psi$ a	ınd	
		$ \psi ^2$ .	[4]	
	(c)	Find the de Broglie wavelength of electron of ener	rgy	
		10 keV.	[3]	
		G.		

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- **7.** Define superconductivity. Distinguish between Type-I and (a)Type-II superconductors. [6]
  - Explain synthesis of nanoparticles using ball milling (*b*) method. [4]
  - two applications of Nanotechnology in brief. [3] (c) Explain any

Or

- How can gold nanoparticles be synthesized using colloidal 8. (a)route? Explain the nucleation and growth of nanoparticles using LaMer diagram. [6]
  - Explain the BCS theory of superconductors. [4]
  - (c) The critical temperature of a superconductor with isotopic mass 200 is 5K. Calculate the critical temperature of superconductor when isotopic mass is 196. [3]